

### **Features**

Contact FormLoad Voltage40 V Max.

• Operation LED Current 3.0mA Max.

• Load Current 2.0A Max.

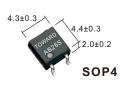
• On-Resistance 0.085ΩTyp.

• Output Capacitance 240 pF Typ.

• Low Off-State Leakage Current 1.0  $\mu$  A Max.

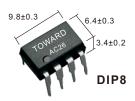
• Suffix - H for DIP/SMD I/O Breakdown Voltage 5000Vrms Min.

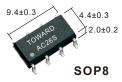
## Outline:(Unit:mm) pitch:2.54 mm





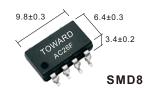












### Terminal Identification電路結構圖

	Terminal Identification	
AB26(F)(S)	AA26(F)	AC26(F)(S)
4 3    1   1   2   (+) (-)	6 5 4 	8 7 6 5 
1: Anode (LED) 2: Cathode (LED) 3,4: Drain (MOS FET)	1: Anode (LED) 2: Cathode (LED) 3: NC 4,6: Drain (MOS FET) 5: Source (MOS FET)	1,3: Anode (LED) 2,4: Cathode (LED) 5,6,7,8: Drain (MOS FET)

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## Absolute Maximum Ratings 絕對最大定格 (Ambient Temperature 周圍溫度:25℃)

	Item	Symbol	Value				
Outline Package			SMD 4/8 SI			DIP 6 SMD 6 1CH	
	Continuous LED Current 連續的LED電流	lF	1011	2011	50mA	2011	1011
Input	Peak LED Current LED的峰值電流f=100 Hz, duty=1%)	IFP	500mA				
輸入	LED Reverse Voltage 逆向的LED電壓	VR	5V				
	Input Power Dissipation 容許損失	Pln	75mW				
	Load Voltage 負荷電壓	VL	40V (AC peak or DC)				
Output	Load Current 負荷電流 (A	) IL	2.0	1.6	2.0	2.0	2.0
輸出	Peak Load Current 峰值負荷電流 (1 ms,1 shot) (A	l <sub>Peak</sub>	5.0	5.0	5.0	5.0	5.0
	Output Power Dissipation 電流損耗 (mW	Pout	350	450	450	600	450
Total Power Dissipation 全損耗 (mW)			400	500	500	650	500
I/O Breakdown Voltage 入/出力間絕緣電壓 (Vrms)			1500	1500	3750	3750	3750
Operating Temperature 使用時周圍溫度			-40°C ∼ +85°C				
Storage Temperature 周圍保存溫度			-40°C ~ +100°C				

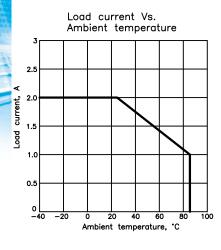
## Electrical Specifications LED順向電壓(Ambient Temperature 周圍溫度 : 25℃)

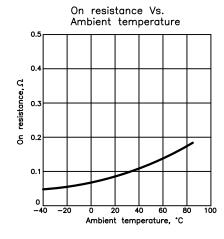
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input 輸入	LED Forward Voltage LED順向電壓	VF	1.0	1.37	1.5	V	I <sub>F</sub> =10mA
	Operation LED Current LED的動作電流	<b>I</b> F On		0.5	3.0	mA	
	Recovery LED Voltage LED的恢復電壓	VF Off	0.5	1.1		V	
Output 輸出	On-Resistance 導通電阻 Drain to Drain	Ron		0.085	0.5	Ω	I <sub>F</sub> =5mA,I <sub>L</sub> =Rating Time to flow is within 1sec.
	Off-State Leakage Current 開路狀態時的電流	lLeak			1.0	μΑ	VL=40V
	Output Capacitance 輸出端容量	Cout		240		pF	VL=0V, f=1MHz
Transmission 傳達	Turn-On Time 動作時間	Ton		0.5	2.5	ms	I==5mA
	Turn-Off Time 復位時間	Toff		0.04	0.5	ms	I <sub>L</sub> =Rating (for SOP type)
	Turn-On Time 動作時間	Ton		0.5	2.5	ms	IF=10mA, IL=Rating
	Turn-Off Time 復位時間	Toff		0.05	0.5	ms	(for DIP/SMD type)
Coupled 結合	I/O Insulation Resistance 輸入/出間的絕緣阻抗	Rı/o	10°			Ω	
	I/O Capacitance 輸入/力端的靜電容量	Cı/o		1.3		pF	f=1MHz

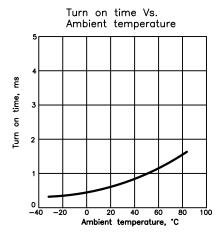
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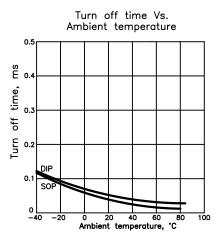
## 26 Series

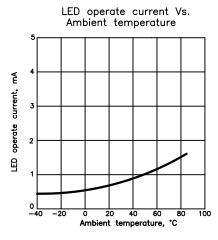
### **PhotoDMOS Relay**

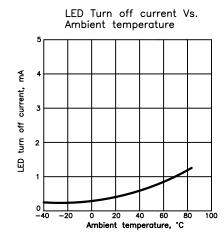


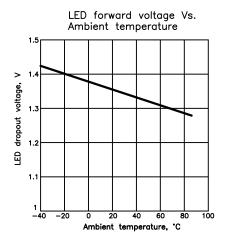


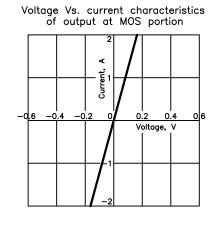


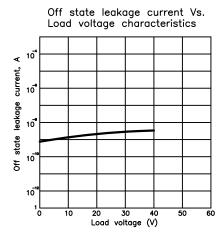


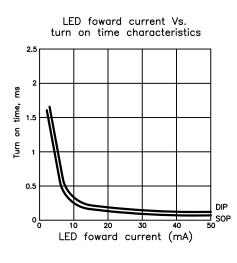


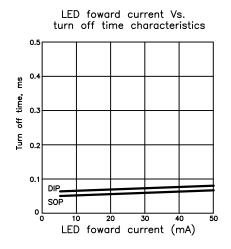


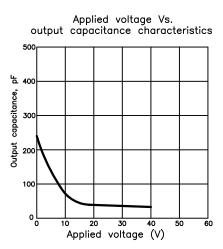






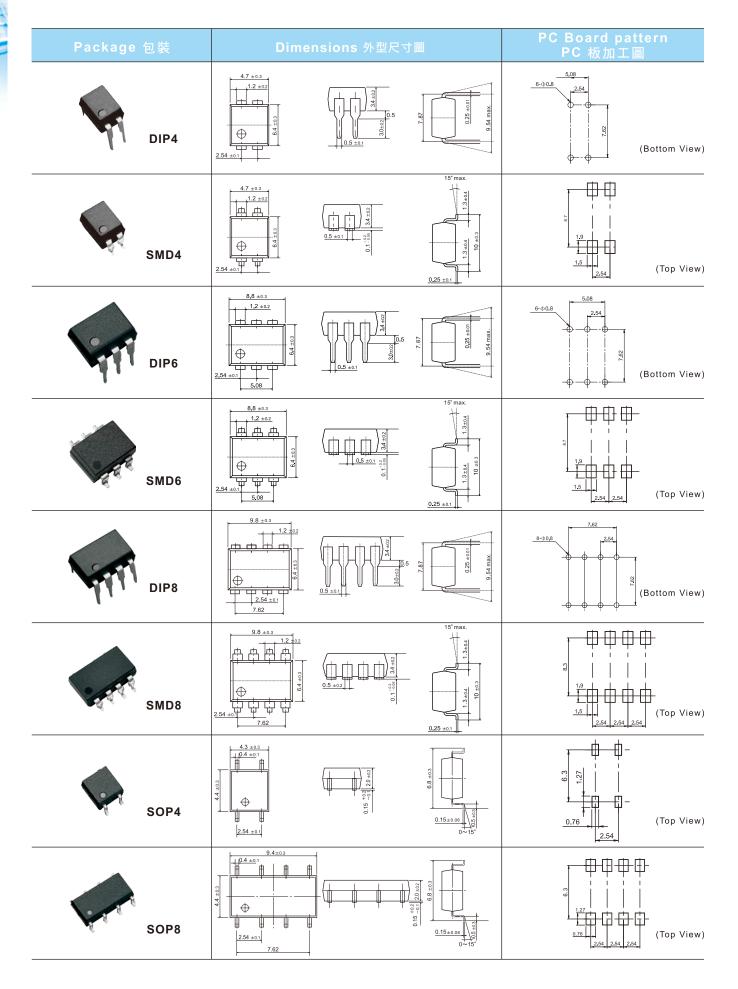






hotoDMOS-FET Hi-Current

## Package & PC Board Pattern



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# Packing Specifications

Package Type 包 裝 類 型	Tape shape & dimensions 形 狀 和 尺 寸	Reel shape &dimensions 圈 帶 形 狀 和 尺 寸	Quantity 數 量
4 Pin SOP	the description of the latest the	2 <u>021</u>	1000 pcs
8 Pin SOP	0.1.5  R1 Feed Direction  R2 Feed Direction  O O O O O O O O O O O O O O O O O O O	17 20 0 013	1000 pcs
4 Pin SMD	01.5  01.5  0.3  0.3  0.3  0.3  0.0  0.3  0.0  0.1.5  0.0  0.1.5  0.0  0.0  0.0	2 <u>0.21</u>	1000 pcs
6 Pin SMD	0.3	17 2.2 ©21	1000 pcs
8 Pin SMD	Ot 1.5  Ot 1.5  Ot 1.5  Ot 1.5  Red Direction	17 2.2 0.21 0.13	1000 pcs

## **Load Connecting Method**

Type 類 型		Load 負 荷	Connection 接續方法	Feature 特 長		
4pin	AC or DC		LOAD VL(AC or DC)	Control bi-directional signal 可控制雙向信號		
	A AC or DO		LOAD VL(AC or DC)	Control bi-directional signal 可控制雙向信號		
6pin	В	DC	LOAD V.(DC)	On-Resistance is 1/2 of A-connection  導通電阻值是A接法的1/2 2-Make-contacts		
			LOAD VL(DC)	(Source Common)		
	С	DC	V <sub>L</sub> (DC)	On-Resistance is 1/2 of B-connection 導通電阻值是B接法的1/2		
gnin	AC or DC		UCAD V.(AC or DC)	2 input and 2 output 2入力和2出力回路		
8pin			VL(AC or DC)  VL(AC or DC)	1 input and 2 output 1入力和2出力回路		